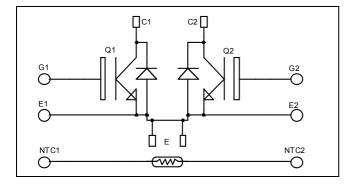


Dual common source Trench + Field Stop IGBT3 Power Module



F2 fi

G2 n

 $V_{CES} = 1700V$ $I_{C} = 100A$ @ Tc = 80°C

Application

- AC Switches
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration
- Internal thermistor for temperature monitoring



- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1700	V
Ţ	Continuous Collector Current	$T_C = 25^{\circ}C$	150	
I_{C}	Continuous Conector Current	$T_C = 80$ °C	100	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	200	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	560	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	200A @ 1600V	

(0

C2

C2

NTC2

NTC1

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$				250	μA
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		2.0	2.4	V
$V_{CE(sat)}$	Conector Emitter Saturation Voltage	$I_C = 100A$	$T_j = 125$ °C		2.4		`
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 2mA$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE}$	=0V			400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			9		
C_{oes}	Output Capacitance	$V_{CE} = 25V$			0.36		nF
C _{res}	Reverse Transfer Capacitance	f = 1MHz			0.3		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)			370		
T_{r}	Rise Time	$V_{GE} = 15V$			40		ns
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 900V$ $I_{\text{C}} = 100A$			650		
T_{f}	Fall Time	$R_G = 4.7 \Omega$		180			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$			400		
T_{r}	Rise Time				50		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 900V$ $I_{C} = 100A$			800		ns
T_{f}	Fall Time	$R_G = 4.7 \Omega$			300		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 900V$	$T_j = 125$ °C		32		I ees
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy	$I_C = 100A$ $R_G = 4.7 \Omega$	$T_j = 125$ °C		31		mJ

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1700			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1700V	$T_j = 25^{\circ}C$			250	μА
1KM		VR 1700 V	$T_j = 125$ °C			500	μ1
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		100		A
V_{F}	Diode Forward Voltage	$I_{\rm F} = 100A$	$T_j = 25^{\circ}C$		1.8	2.2	V
V F	Blode I of ward Voluge	1 _F 10071	$T_{i} = 125^{\circ}C$		1.9		,
t _{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		385		ns
чт	reverse recovery Time		$T_j = 125$ °C		490		115
0	Reverse Recovery Charge	$I_F = 100A$ $V_R = 900V$ $di/dt = 1000A/\mu s$	$T_j = 25^{\circ}C$		25		μС
Q_{rr}			$T_j = 125$ °C		42		μС
E	Reverse Recovery Energy		$T_j = 25$ °C		11		mJ
E_{r}			$T_j = 125$ °C		21		1113



Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

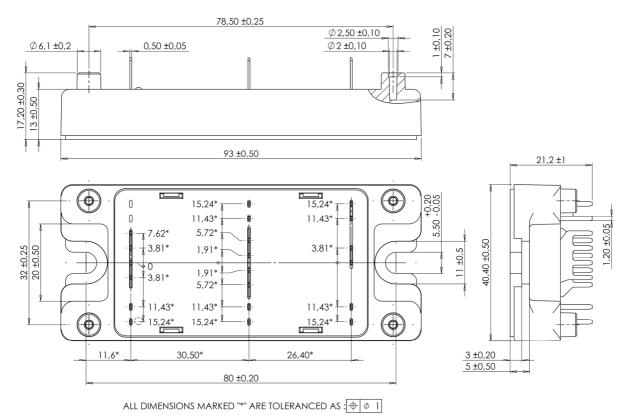
Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		IGBT		0.22	°C/W	
1\(\text{thJC}\)			Diode		0.39		
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight					160	g

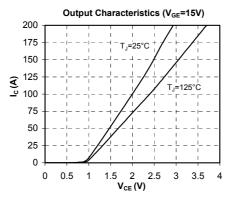
SP4 Package outline (dimensions in mm)

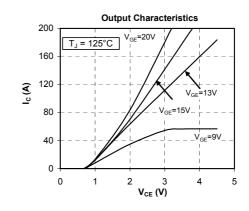


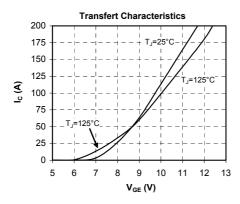
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

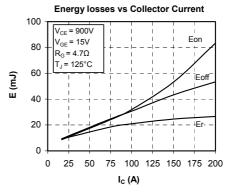


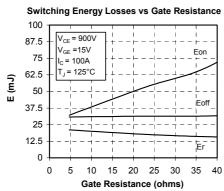
Typical Performance Curve

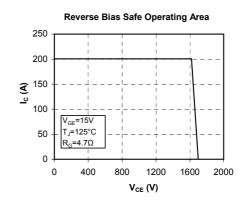


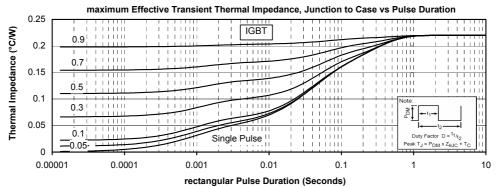




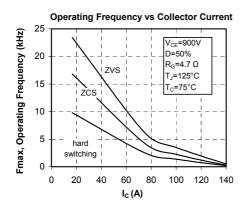


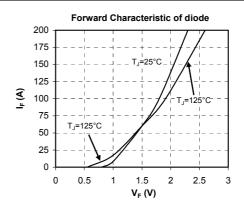


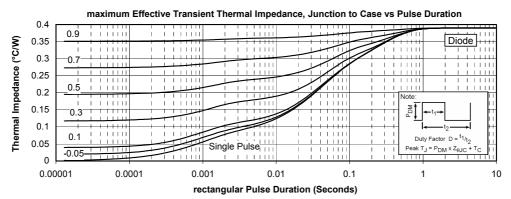












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